Lecture
Crystal growth: Physics, technology, and modeling
Academic year 2026-2027 Semester I

Stanisław Krukowski
IWC PAN, Sokołowska 29/37 01-142 Warszawa

Zbigniew Żytkiewicz
IF PAN, Al. Lotników 32-46 02-668 Warszawa

http://www.unipress.waw.pl/~stach/cg-2026-27/

Description

The development of information technologies, includes the design and fabrication of new electronic devices of nanometer size, the emergence of new molecular diagnostic techniques (e.g. for medical purposes) requires understanding of the basics of the methods of design and fabrication of the new materials and structures. This course will cover problems of the understanding, design, fabrication and determination of the properties of nano-structures and nano-materials, forming an introduction to nanotechnology. Therefore the subject of the lecture will be devoted to the basic methods of crystal growth, both volumetric, at the macro scale, and quantum structures of the dimensions in micro and nano range. Currently, courses in physics, chemistry or material engineering in Poland, both in Warsaw and in other cities, do not include lectures on the fundamentals of crystal growth. Therefore the students working in these areas need additional training. The program proposed below includes a course in the fundamentals of crystal growth (especially of semiconductors), both from a theoretical point of view and a review of the main growth techniques and characterization methods. We assume that this course will not be an exhaustive description of the subject. Instead, it will provide a sufficient foundation for understanding the field, while providing a good starting point for further independent study in the future research work. The course is intended for PhD students that they have mastered the basics of quantum mechanics, statistical mechanics and solid state physics at the university level. At the end of the year-long lecture series we foresee a visit of the students to the crystal growth laboratories of the Institute of Physics PAS and the Institute of High Pressure Physics PAS in Warsaw. This will allow interested students to familiarize themselves with the existing experimental facilities and with details of the research work in progress.

Technical notes

The lectures will be given on Wednesdays at 9.00 in the premises of the Institute of Physics Polish Academy of Sciences.

The links in the title will provide access to pdf file of the lecture. Usually this will be in the preceding week. The student could download the lecture and look BEFORE the lecture. The students are strongly encouraged to do that.

Any students interested in physics and technology, from Warsaw4PhD School, but also from other partner institutions in Warsaw are invited to the lecture.

The inauguration of the Academic Year 2026-27 is planned on Monday October 5th 2026, therefore the first lecture is scheduled Wednesday October 7th 2026.

Semester I (Room D)

1. Growth of semiconductor bulk crystals in Poland and in the world – an overview (Michał Leszczyński - Institute of High Pressure Physics PAS) 07.10.2026

2. Semiconductor epitaxy in Poland and in the world – an overview (Michał Leszczyński - Institute of High Pressure Physics PAS) 14.10.2026

3. Thermodynamic equilibrium (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 21.10.2026

4. Properties of crystal surfaces (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 28.10.2026

5. Thermodynamics of growth processes (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 04.11.2026

6. Kinetic processes at surfaces (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 18.11.2026 & 25.11.2026

7. Growth of semiconductors – *ab initio* based theory (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 02.12.2026

8. Step motion (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 09.12.2026

9. Doping – point defects (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 16.12.2026

10. Dislocations and other extended defects (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 23.12.2026

11. Transport in vapor and liquid phase (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 13.01.2027 & 20.01.2027

12. Shape selection and stability during growth (Stanislaw Krukowski - Institute of High Pressure Physics PAS) 27.01.2027

Semester II (Room D)